

E-SERIES 0805/1206 SMT CHIP INDUCTORS

HIGH Q-FACTOR SERIES 5308/5303







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SUMIDA Components GmbH is a well-known manufacturer of RF electronic components.

Within our product program, we offer standard platforms as well as custom solutions designed and manufactured with the highest level of quality.

This results in robust and reliable components for our cu-

stomers' demanding applications.

Our extensive manufacturing and testing capabilities coupled with our IATF 16949, DIN EN ISO 9001, DIN EN ISO 14001 and DIN EN ISO 50001 certifications, makes SUMIDA Components GmbH the right choice to satisfy your high requirements.

GENERAL CHARACTERISTICS OF WIRE-WOUND SMT CHIP INDUCTORS

DESCRIPTION

This series are characterised by an excellent price/performance ratio. The E-Series SMT Chip Inductors are highly reliable inductive component solutions for mass production of electronic circuits for smart system suppliers of the electronic industry (Non-Automotive applications). The series 5308/5303 are wire-wound Chip Inductors on a smaller aluminiumoxide ceramic body. The terminal metallization is AgPd/Ni/Au.

FEATURES

- · Small Sizes for SMT
- · Stable Inductance even in High Frequencies
- Tight Tolerances
- · Low DC Resistance
- Operating Temperature Range -40 °C to +85 °C
- · High Q-Factor
- · Low Capacitor Behaviour

APPLICATIONS

- Antenna Amplifier
- Mobile Phones (GSM)
- Global Positioning Systems (GPS)
- Digital Cameras

QUALITY MANAGEMENT SYSTEM

Certified QM-System: IATF 16949 DIN EN ISO 9001 Certified EM-System: DIN EN ISO 14001 DIN EN ISO 50001



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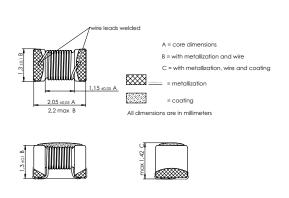
HIGH Q-FACTOR SERIES 5308/5303

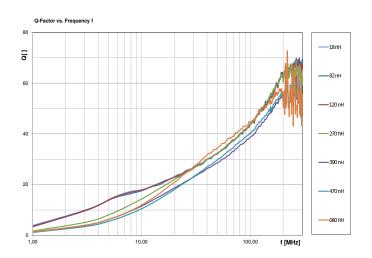
ELECTRICAL PARAMETERS

	symbol	0805 (2012)	1206 (3216)
Inductance	L	18 680 nH	82 270 nH
Tolerance (depends on L-Value)	-	2/5/10/20 %	2/5/10/20 %
Minimum Q-factor	Q _{min}	30 45	33 45
Self Resonance Frequency	f _{res, min}	> 3850 500 MHz	> 1500 950 MHz
Max. DC Resistance	R _{DC, max}	120 3400 mΩ	200 520 m $Ω$
Rated Current (ref. to 85 °C)	rated	850 170 mA	900 630 mA
Operating Temperature Range	-	-40 +85 °C	-40 +85 °C

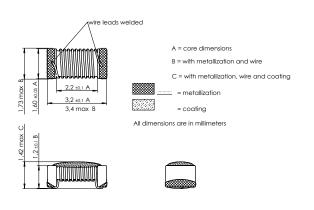
Further L-Values and Tolerances on request

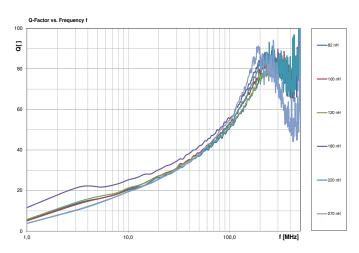
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